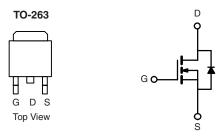


www.vishay.com

Vishay Siliconix

Automotive N-Channel 75 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	75				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0048				
I _D (A)	120				
Configuration	Single				



FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualifiedd
- 100 % R_q and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



N-Channel	MOCEE
N-Channel	MUSEE

ORDERING INFORMATION				
Package	TO-263			
Lead (Pb)-free and Halogen-free	SQM120N08-05-GE3			

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V_{DS}	75	V	
Gate-Source Voltage	V _{GS}	± 20			
Continuous Drain Current	T _C = 25 °C ^a	-	120		
Continuous Drain Current	T _C = 125 °C	- I _D	106		
Continuous Source Current (Diode Conduction)a	Is	120	А		
Pulsed Drain Current ^b		I _{DM}		480	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	66		
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	217	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	Pn	375	W	
wiaximum Fower Dissipations	T _C = 125 °C	ı D	125		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient F	PCB Mount ^c	R_{thJA}	40	°C/W	
Junction-to-Case (Drain)		R_{thJC}	0.4		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		75	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		-	4.0	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = 75 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 75 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 75 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	120	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0039	0.0048		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0087	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0110	•	
Forward Transconductance ^{a, b}	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	102	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	8158	10 200		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	865	1085	pF	
Reverse Transfer Capacitance	C _{rss}			-	567	710		
Total Gate Charge ^c	Qg			-	141	212		
Gate-Source Charge ^c	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 35 \text{ V}, I_D = 110 \text{ A}$	-	32.6	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	39.1	-		
Gate Resistance	R _g		f = 1 MHz		1.2	1.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}	V_{DD} = 35 V, R_L = 0.32 Ω I_D \cong 110 A, V_{GEN} = 10 V, R_g = 1 Ω		-	19	29		
Rise Time ^c	t _r			-	31	47	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	55	83		
Fall Time ^c	t _f			-	15	23		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	480	Α	
Forward Voltage	V_{SD}	I _F =	_	0.9	1.5	V		

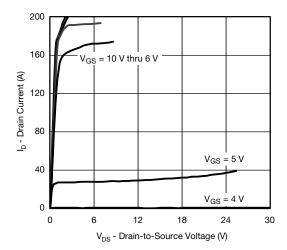
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

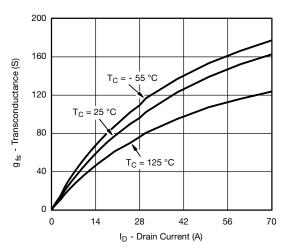
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



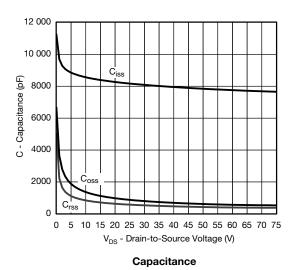
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

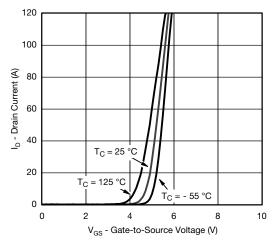


Output Characteristics

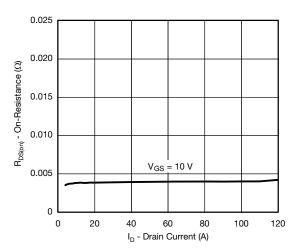


Transconductance

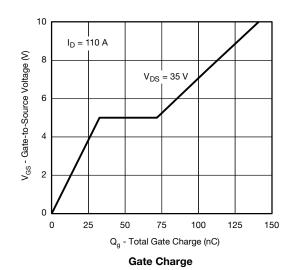




Transfer Characteristics

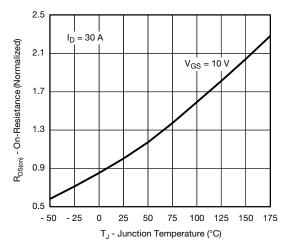


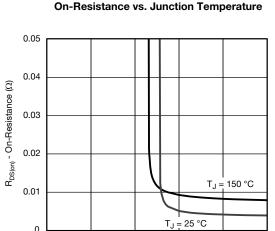
On-Resistance vs. Drain Current





TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



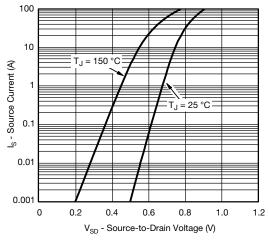


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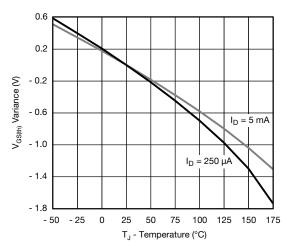
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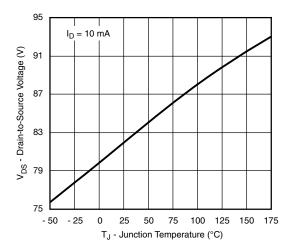
 V_{GS} - Gate-to-Source Voltage (V) On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage

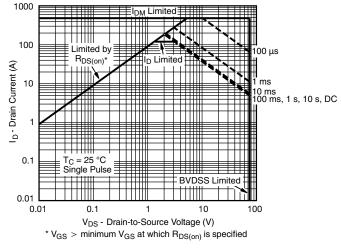


10

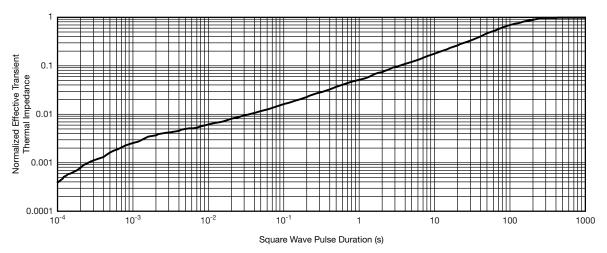
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



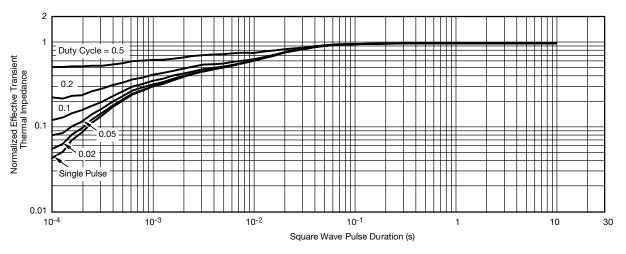
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

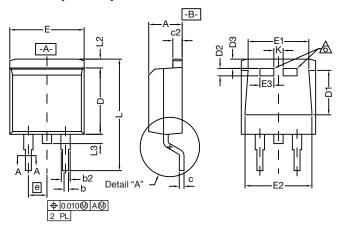
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

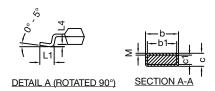
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TO-263 (D²PAK): 3-LEAD





		INCHES		MILLIN	METERS	
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
D1		0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
E		0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
	е	0.100	0.100 BSC		BSC	
	K	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
М		-	0.002	-	0.050	
	ECN: T10-0738-Rev. J, 03-Jan-11 DWG: 5843					

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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